## E3D20065D

## Silicon Carbide Schottky Diode E-Series Automotive

## Features

- 650-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on $\mathrm{V}_{\mathrm{F}}$


## Benefits

- Higher System Level Efficiency
- Increase System Power Density
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway



## Applications

- Automotive and Traction Power Conversion
- Battery Charging Systems
- Boost Diode in PFC or DC/DC Stages
- Free Wheeling Diodes in Inverter Stages
- AC/DC Converters

| Part Number | Package | Marking |
| :---: | :---: | :---: |
| E3D20065D | TO-247-3 | E3D20065D |

- PV Inverters
8.0Maximum Ratings ( $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ unless otherwise specified)

| Symbol | Parameter | Value | Unit | Test Conditions | Note |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {RRM }}$ | Repetitive Peak Reverse Voltage | 650 | V |  |  |
| $\mathrm{V}_{\mathrm{R}}$ | DC Peak Reverse Voltage | 650 | V |  |  |
| $I_{\text {F }}$ | Continuous Forward Current | 28*/56** 13*/26** 10*/20** | A | $\begin{aligned} & \mathrm{T}_{\mathrm{c}}=25^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{C}}=135^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{c}}=150^{\circ} \mathrm{C} \\ & \hline \end{aligned}$ | Fig. 3 |
| $\mathrm{P}_{\text {tot }}$ | Power Dissipation | $\begin{gathered} 122^{*} \\ 53^{*} \end{gathered}$ | W | $\begin{aligned} & \mathrm{T}_{\mathrm{c}}=25^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{C}}=110^{\circ} \mathrm{C} \end{aligned}$ | Fig. 4 |
| $\mathrm{I}_{\text {FRM }}$ | Repetitive Peak Forward Surge Current | $\begin{aligned} & 37^{*} \\ & 22^{*} \end{aligned}$ | A | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}, \mathrm{t}_{\mathrm{P}}=10 \mathrm{~ms}$, Half Sine Pulse $\mathrm{T}_{\mathrm{c}}=110^{\circ} \mathrm{C}, \mathrm{t}_{\mathrm{p}}=10 \mathrm{~ms}$, Half Sine Pulse |  |
| $\mathrm{dV} / \mathrm{dt}$ | Diode dV/dt ruggedness | 200 | V/ns | $\mathrm{V}_{\mathrm{R}}=0-650 \mathrm{~V}$ |  |
| $\mathrm{T}_{\mathrm{j}}, \mathrm{T}_{\text {stg }}$ | Operating Junction and Storage Temperature | $\begin{gathered} -55 \text { to } \\ +175 \end{gathered}$ | ${ }^{\circ} \mathrm{C}$ |  |  |
|  | TO-247 Mounting Torque | $\begin{gathered} 1 \\ 8.8 \end{gathered}$ | $\underset{\mathrm{lbf-in}}{\mathrm{Nm}}$ | M3 Screw 6-32 Screw |  |

* Per Leg, ** Per Device


## CREE -

## Electrical Characteristics

| Symbol | Parameter | Typ. | Max. | Unit | Test Conditions | Note |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{F}$ | Forward Voltage | $\begin{aligned} & 1.5^{*} \\ & 2.0^{*} \end{aligned}$ | $\begin{aligned} & 1.8^{*} \\ & 2.4^{*} \end{aligned}$ | V | $\begin{aligned} & \mathrm{I}_{\mathrm{F}}=10 \mathrm{~A} \quad \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \\ & \mathrm{I}_{\mathrm{F}}=10 \mathrm{~A} \quad \mathrm{~T}_{\mathrm{J}}=175^{\circ} \mathrm{C} \end{aligned}$ | Fig. 1 |
| $I_{R}$ | Reverse Current | $\begin{aligned} & 12^{*} \\ & 24^{*} \end{aligned}$ | $\begin{gathered} 60^{*} \\ 220^{\star} \end{gathered}$ | $\mu \mathrm{A}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{R}}=650 \mathrm{~V} \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \\ & \mathrm{~V}_{\mathrm{R}}=650 \mathrm{~V} \mathrm{~T}_{\mathrm{J}}=175^{\circ} \mathrm{C} \\ & \hline \end{aligned}$ | Fig. 2 |
| $\mathrm{Q}_{\mathrm{c}}$ | Total Capacitive Charge | 28* |  | nC | $\begin{aligned} & V_{R}=400 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=10 \mathrm{~A} \\ & \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \end{aligned}$ | Fig. 5 |
| C | Total Capacitance | $\begin{gathered} \hline 459^{\star} \\ 55^{\star} \\ 49^{\star} \end{gathered}$ |  | pF | $\begin{aligned} & V_{R}=0 \mathrm{~V}, \mathrm{~T}_{J}=25^{\circ} \mathrm{C}, \mathrm{f}=1 \mathrm{MHz} \\ & \mathrm{~V}_{\mathrm{R}}=200 \mathrm{~V}_{,} \mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}, \mathrm{f}=1 \mathrm{MHz} \\ & \mathrm{~V}_{\mathrm{R}}=400 \mathrm{~V}_{,} \mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}, \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ | Fig. 6 |
| $\mathrm{E}_{\mathrm{c}}$ | Capacitance Stored Energy | 4.5* |  | $\mu \mathrm{J}$ | $\mathrm{V}_{\mathrm{R}}=400 \mathrm{~V}$ | Fig. 7 |

Note: This is a majority carrier diode, so there is no reverse recovery charge.

## Thermal Characteristics

| Symbol | Parameter | Typ. | Unit | Note |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{R}_{\text {өJC }}$ | Thermal Resistance from Junction to Case | $1.23^{*}$ <br> $0.62^{\star *}$ | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ | Fig. 8 |

* Per Leg, ** Per Device


## Typical Performance (Per Leg)



Figure 1. Forward Characteristics


Figure 2. Reverse Characteristics

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## Typical Performance (Per Leg)



Figure 3. Current Derating


Figure 5. Recovery Charge vs. Reverse Voltage


Figure 4. Power Derating


Figure 6. Capacitance vs. Reverse Voltage

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## Typical Performance (Per Leg)



Figure 7. Typical Capacitance Stored Energy


Figure 8. Transient Thermal Impedance

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## Package Dimensions

Package TO-247-3


| POS | Inches |  | Millimeters |  |
| :---: | :---: | :---: | :---: | :---: |
|  | Min | Max | Min | Max |
| A | . 190 | . 205 | 4.83 | 5.21 |
| A1 | . 090 | . 100 | 2.29 | 2.54 |
| A2 | . 075 | . 085 | 1.91 | 2.16 |
| b | . 042 | . 052 | 1.07 | 1.33 |
| b1 | . 075 | . 095 | 1.91 | 2.41 |
| b3 | . 113 | . 133 | 2.87 | 3.38 |
| C | . 022 | . 027 | 0.55 | 0.68 |
| D | . 819 | . 831 | 20.80 | 21.10 |
| D1 | . 640 | . 695 | 16.25 | 17.65 |
| D2 | . 037 | . 049 | 0.95 | 1.25 |
| E | . 620 | . 635 | 15.75 | 16.13 |
| E1 | . 516 | . 557 | 13.10 | 14.15 |
| E2 | . 145 | . 201 | 3.68 | 5.10 |
| E3 | . 039 | . 075 | 1.00 | 1.90 |
| E4 | . 487 | . 529 | 12.38 | 13.43 |
| e | . 214 BSC |  | 5.44 BSC |  |
| L | . 780 | . 800 | 19.81 | 20.32 |
| L1 | . 161 | . 173 | 4.10 | 4.40 |
| N | 3 |  |  |  |
| $\emptyset Р$ | . 138 | . 144 | 3.51 | 3.65 |
| Q | . 216 | . 236 | 5.49 | 6.00 |
| S | . 238 | . 248 | 6.04 | 6.30 |
| T | $17.5^{\circ} \mathrm{REF}$ |  |  |  |
| W | $3.5{ }^{\circ} \mathrm{REF}$ |  |  |  |
| X | $4^{\circ} \mathrm{REF}$ |  |  |  |

## Recommended Solder Pad Layout



| Part Number | Package | Marking |
| :---: | :---: | :---: |
| E3D20065D | TO-247-3 | E3D20065D |

TO-247-3

Note: Recommended soldering profiles can be found in the applications note here: http://www.wolfspeed.com/power_app_notes/soldering

## Notes

## - RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented January 2, 2013. RoHS Declarations for this product can be obtained from your Wolfspeed representative or from the Product Ecology section of our website at http://www.wolfspeed.com/power/tools-and-support/product-ecology.

- REACh Compliance

REACh substances of high concern (SVHCs) information is available for this product. Since the European Chemical Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future,please contact a Cree representative to insure you get the most up-to-date REACh SVHC Declaration. REACh banned substance information (REACh Article 67) is also available upon request.

- This product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control systems, or air traffic control systems.


## Related Links

- Wolfspeed E-Series Family: http//wolfspeed.com/E-Series
- Wolfspeed SiC Schottky diode portfolio: http://www.wolfspeed.com/Power/Products\#SiCSchottkyDiodes
- Schottky diode Spice models: http://www.wolfspeed.com/power/tools-and-support/DIODE-model-request2
- $\quad \mathrm{SiC}$ MOSFET and diode reference designs: http://go.pardot.com/l/101562/2015-07-31/349i


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